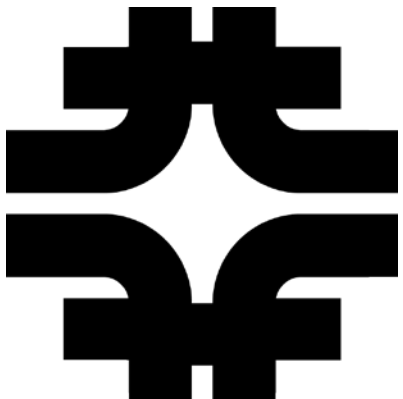


Status of GeantV Integration in CMSSW

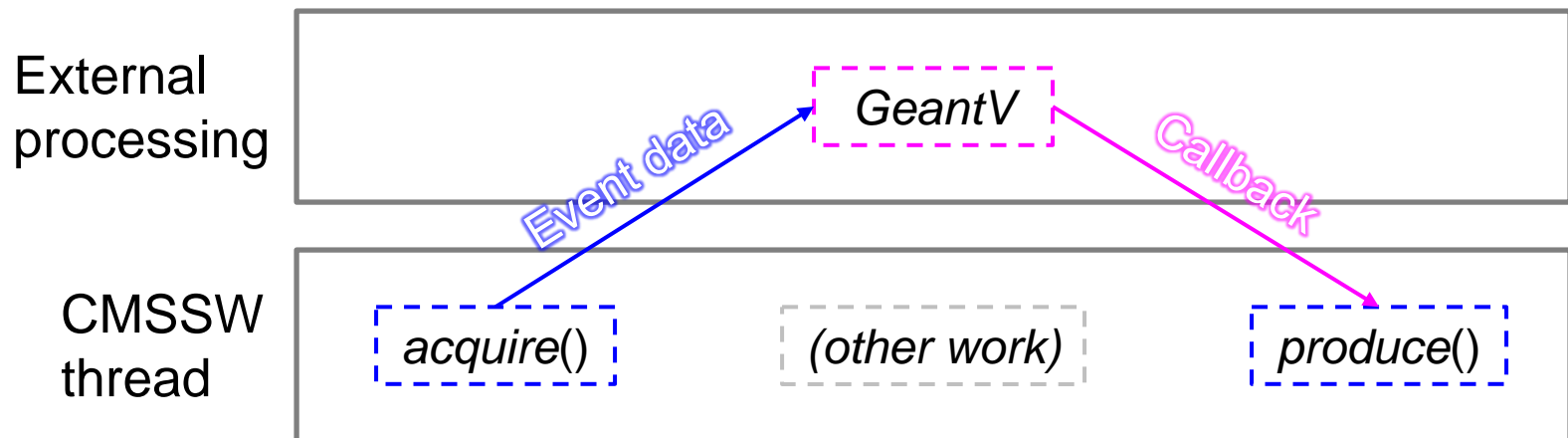
Kevin Pedro, Sunanda Banerjee
(FNAL)

September 13, 2019



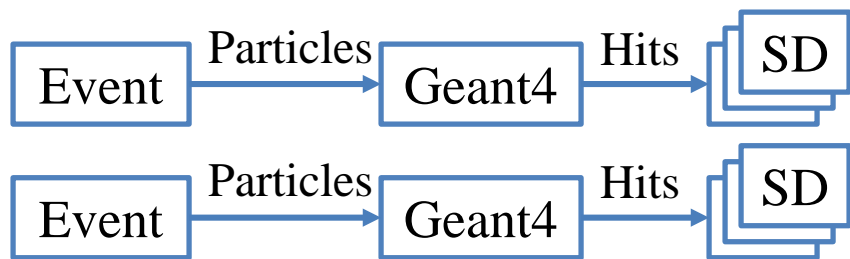
GeantV Integration in CMSSW

- Repositories: [install-geant](#), [SimGVCORE](#)
- ✓ **Generate** events in CMSSW framework, convert HepMC to GeantV format
- ✓ Build **CMSSW geometry** natively and pass to GeantV engine (using TGeo)
- Using **constant magnetic field**, limited **EM-only physics list**
- ✓ **Calorimeter scoring** adapted
- ✓ Run GeantV using **CMSSW ExternalWork** feature:
 - Asynchronous, non-blocking, task-based processing

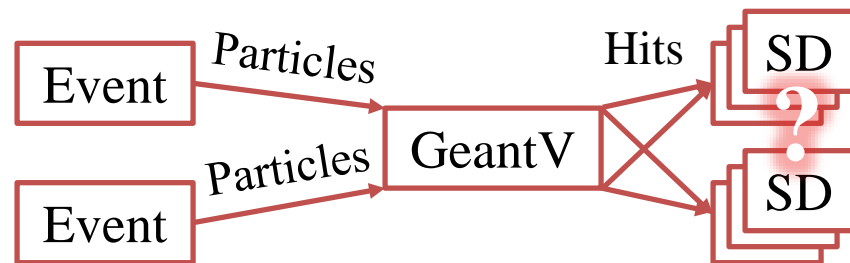


Geant4 vs. GeantV Scoring

- **Sensitive detectors** (SD) and **scoring** trickiest to adapt
 - Necessary to test “full chain” (simulation → digitization → reconstruction)
 - Significantly more complicated than Geant4 MT



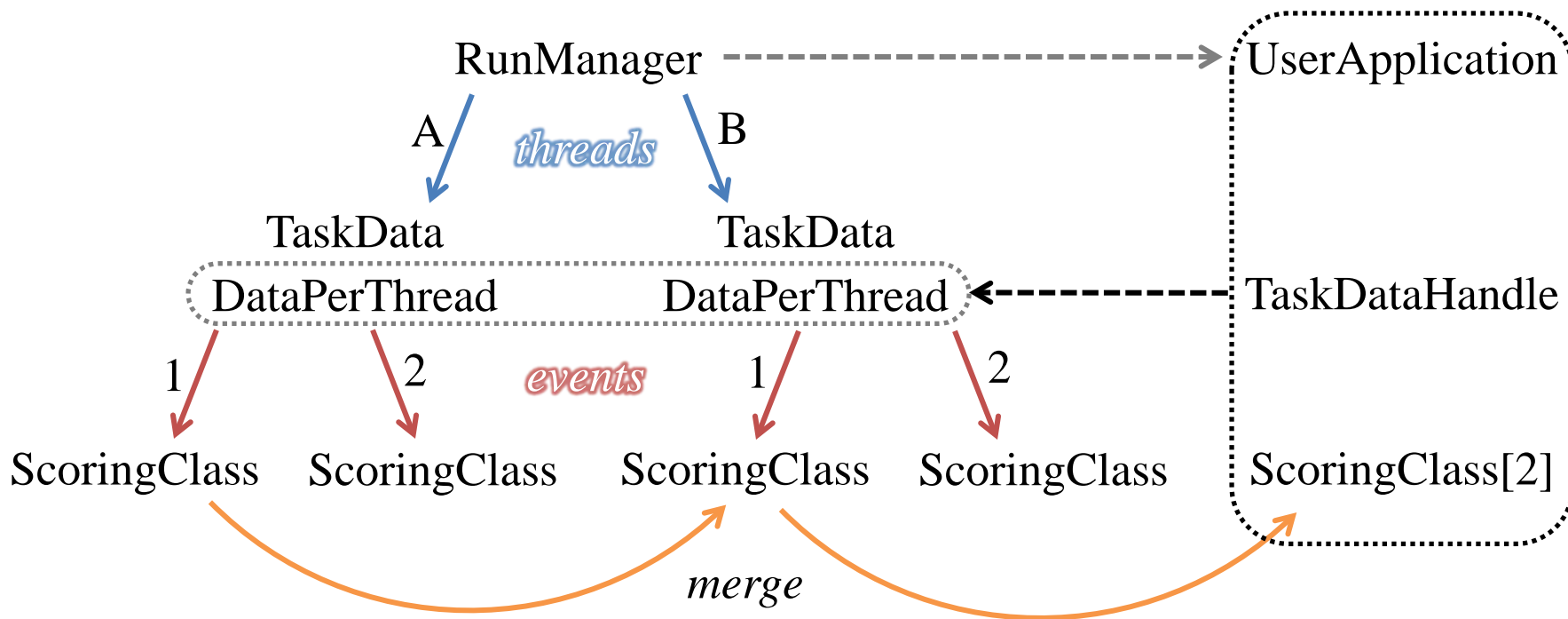
Geant4 shares memory, but each event processed in separate thread



Each event processed in multiple threads, mixed in with other events

- Duplicate SD objects per event per thread, then aggregate
 - 4 streams, 4 threads = 16 SD objects
 - GeantV TaskData supports this approach
- Use template wrappers to unify interfaces and operations
 - Avoid upsetting delicate and complicated SD code, minimize overhead
 - See backup for more details

GeantV Data Aggregation



- Each `ScoringClass` object has instance of `CaloSteppingAction`
 - Some additional memory overhead from duplicated class members
- GeantV assigns slot number to each event
 - May not match stream number in CMSSW, keep track w/ `StreamCache`
- Merged `ScoringClass` object in `UserApp` puts output products into event

Testing GeantV in CMSSW

- Need to validate physics and measure CPU and memory performance
- Previously saw discrepancy in # hits (more in GV than G4)
- Investigated and understood:
 - All CMS-specific G4 optimizations disabled
 - Same **production cuts** (default 1mm)
 - Confirmed intra-simulation reproducibility in single-thread mode (run GV twice on same input, get same output)
 - Found slightly better agreement with magnetic field *disabled* → in single thread mode, but not multithread mode?
 - **Fixed main culprit**: data race in CMS Geant4 application (affected Watchers used for scoring demo , not sensitive detectors used in prod)
- Latest validation results and initial performance results follow

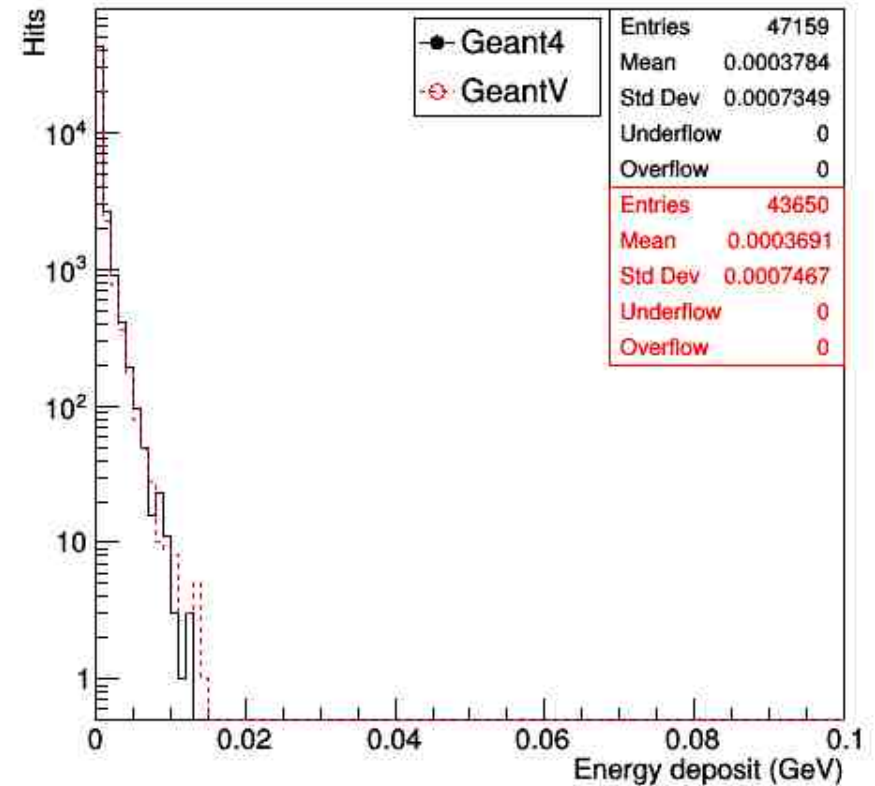
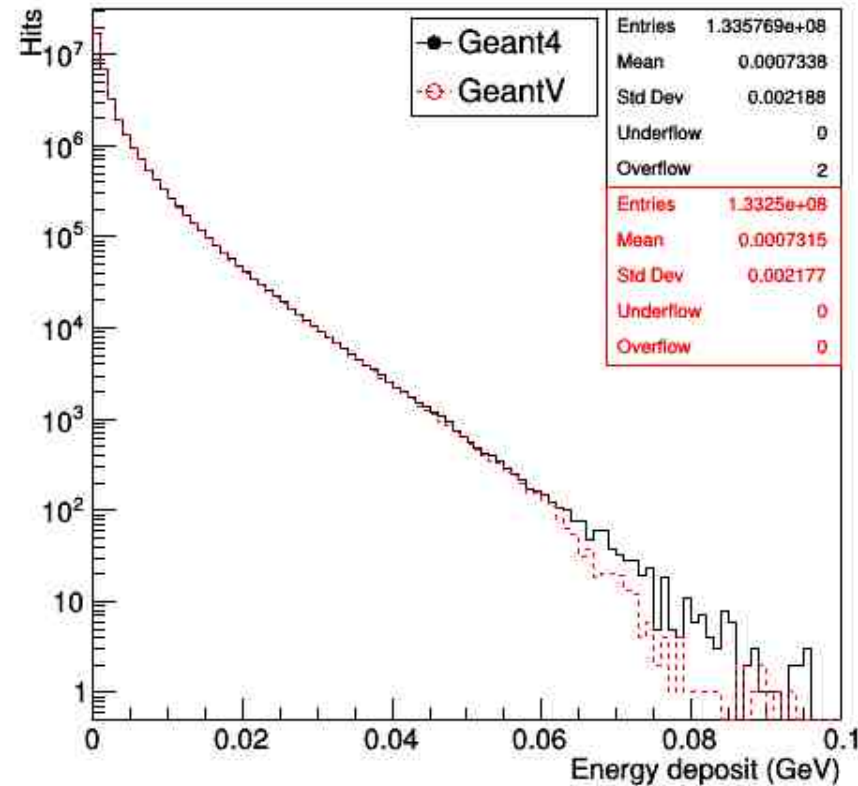
Physics Validation

- Generate 1000 events of single electrons at 100 GeV with a fixed direction ($\eta = 1.0$, $\varphi = 1.1$)
 1. Run Geant4 and GeantV setup on single thread with same input file, $B = 0$ and compare GeantV against Geant4
 2. Compare GeantV against Geant4 for 100 GeV electrons with $B = 3.8$ Tesla
 3. Generate 1000 events of single electrons at 2, 10 and 50 GeV at a fixed direction and compare GeantV against Geant4 with magnetic field off and on at 3.8 Tesla
 4. Generate 100 events of 50 GeV double electrons at 50 GeV with $-3 < \eta < 3$ and $0 < \varphi < 2\pi$, run in multi-threaded mode (4 threads), $B = 0$ Tesla
 5. Repeat multi-threaded test with $B = 3.8$ Tesla

1. Energy Deposits for 100 GeV e- (B=0)

100 GeV Electron B=0 EB (Geant4 vs GeantV)

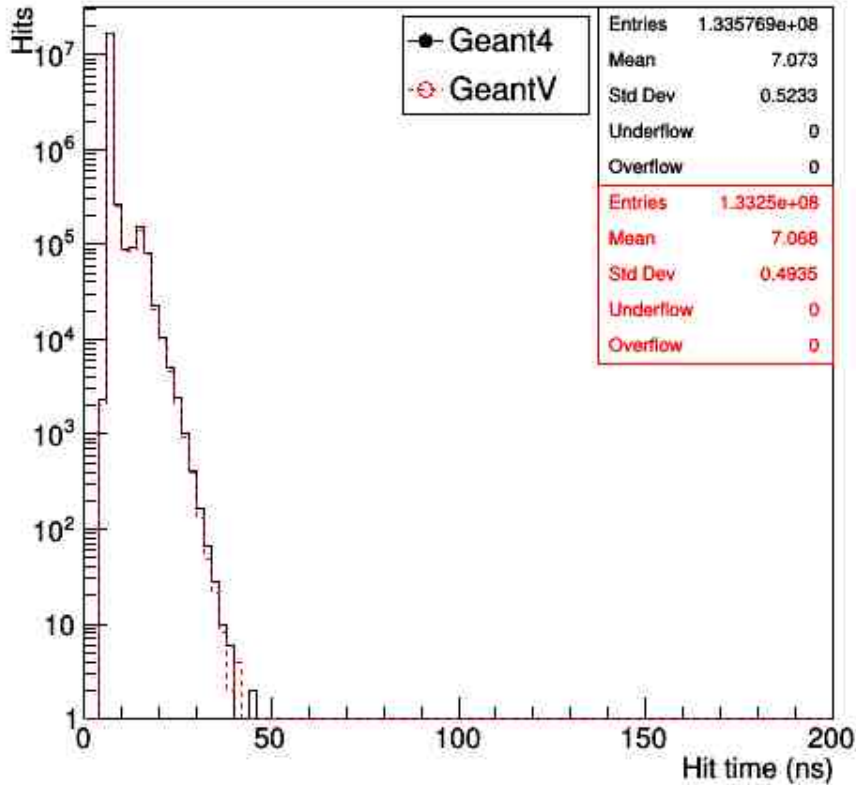
100 GeV Electron B=0 EE (Geant4 vs GeantV)



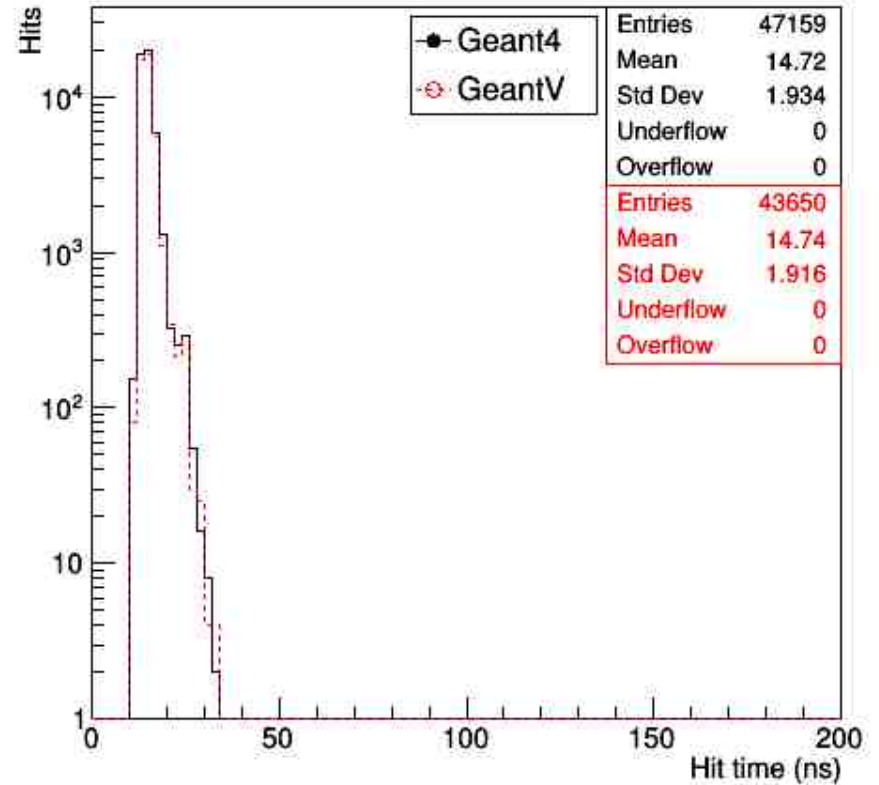
- The number of entries differ by 0.3% (7.4%) in EB (EE) with the electrons going in the barrel
- The means differ by 0.2% for EB and 2.5% for EE

1. Hit Time for 100 GeV e- (B=0)

100 GeV Electron B=0 EB (Geant4 vs GeantV)



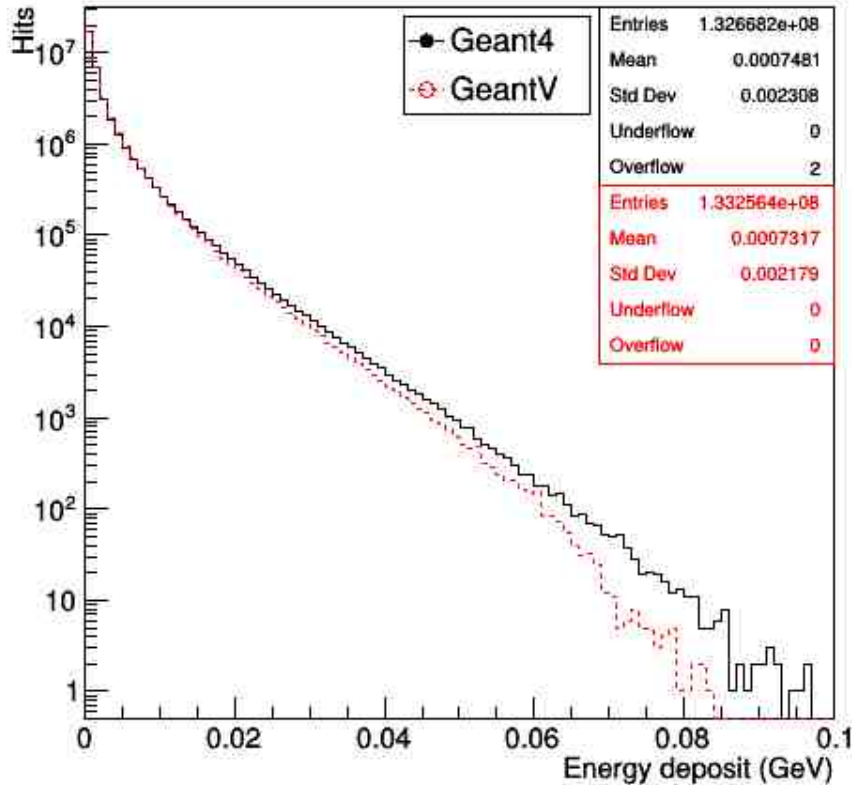
100 GeV Electron B=0 EE (Geant4 vs GeantV)



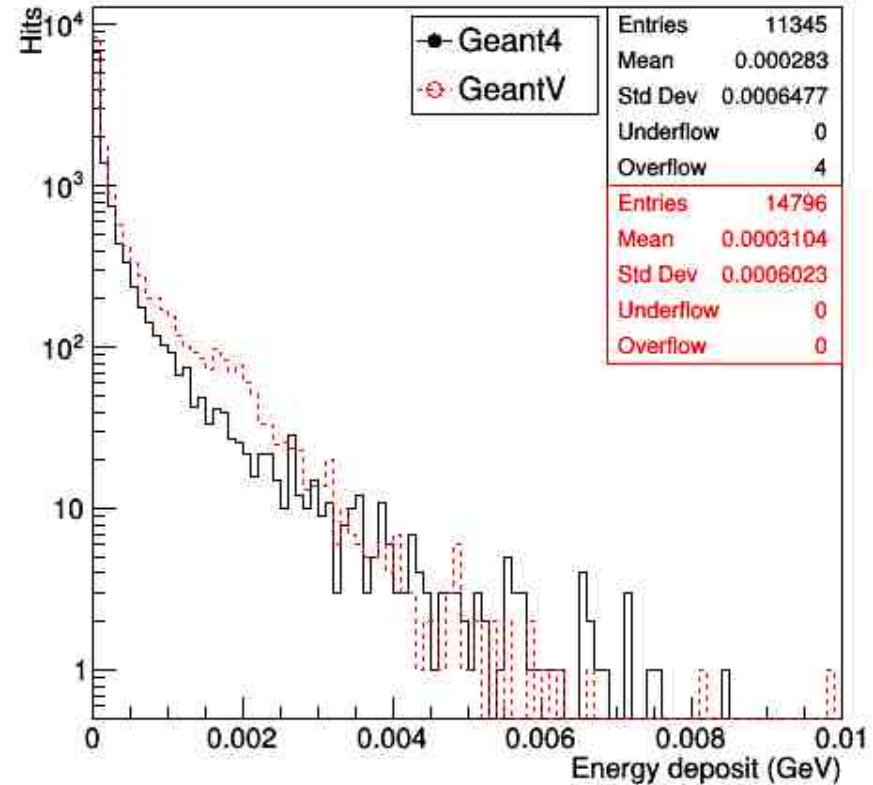
- Means differ by 0.07% for EB and 0.13% for EE with the electrons going in the barrel
- GeantV and Geant4 applications provide roughly the same distributions

2. Energy Deposits for 100 GeV e⁻ (B=3.8)

100 GeV Electron B=3.8 EB (Geant4 vs GeantV)



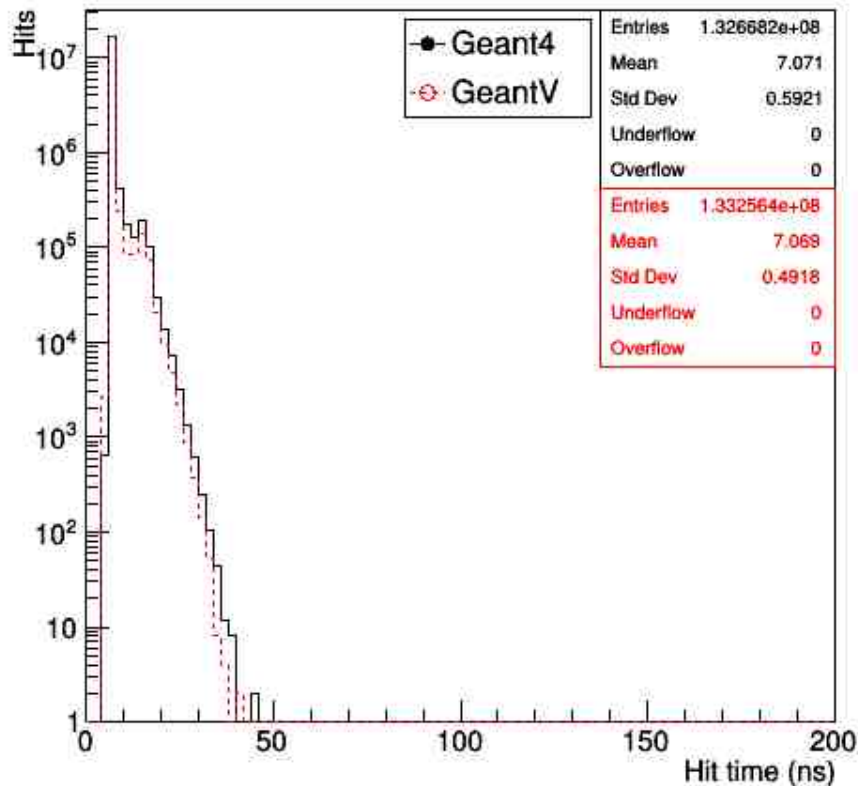
100 GeV Electron B=3.8 HB (Geant4 vs GeantV)



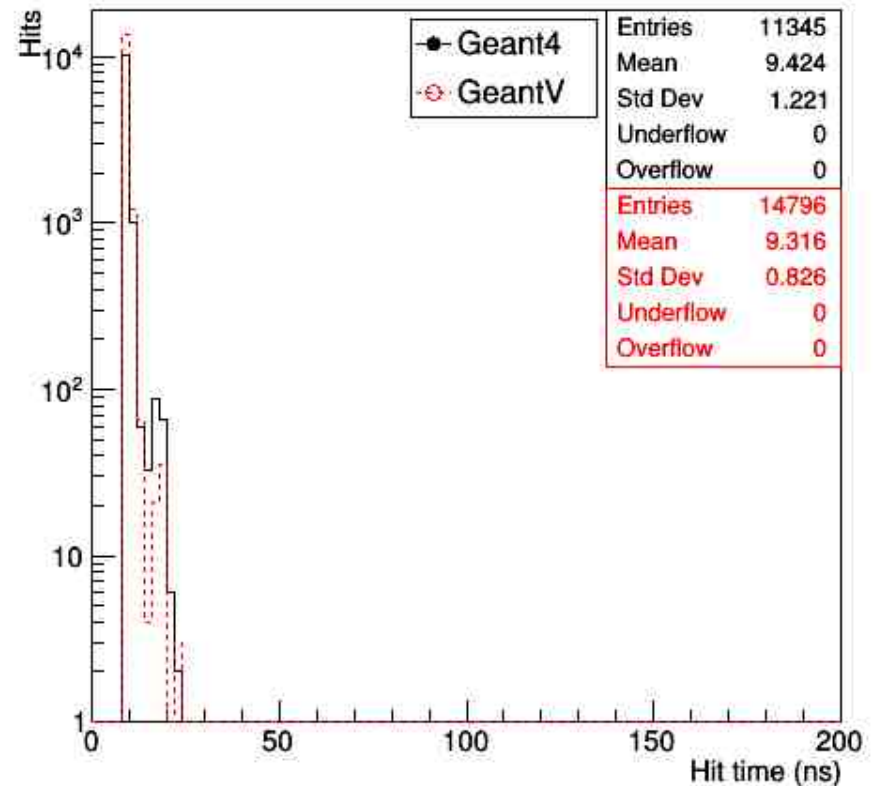
- The number of entries differ by 0.4% (23.3%) in EB (HB) with the electrons going in the barrel
- The means differ by 2.2% for EB and 8.8% for HB

2. Hit Time for 100 GeV e- (B=3.8)

100 GeV Electron B=3.8 EB (Geant4 vs GeantV)



100 GeV Electron B=3.8 HB (Geant4 vs GeantV)

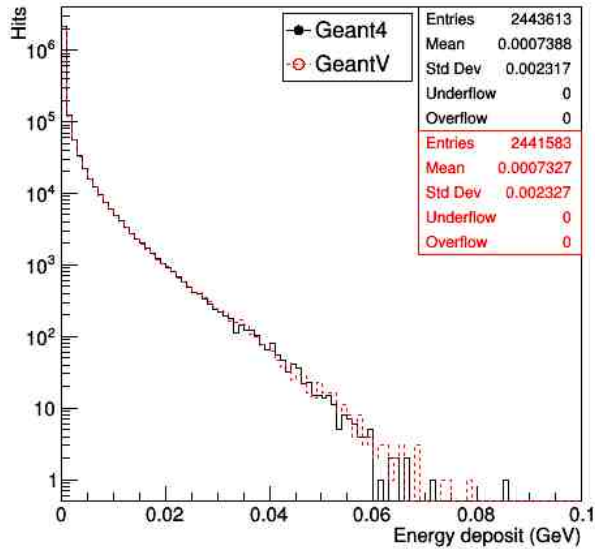


- The means differ by 0.03% for EB and 1.15% for EE with the electrons going in the barrel
- There is a small difference in the physics results of GeantV and Geant4 applications in the presence of B-field

3. Energy Deposit with $B = 0$

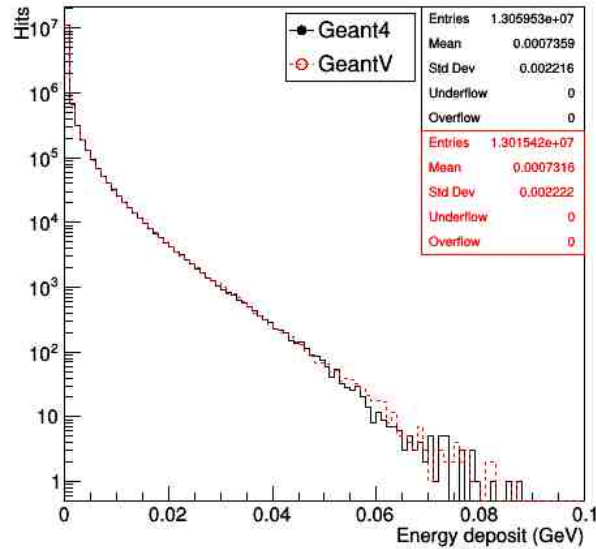
2 GeV Electrons

2 GeV Electrons $B = 0$ EB (Geant4 vs GeantV)



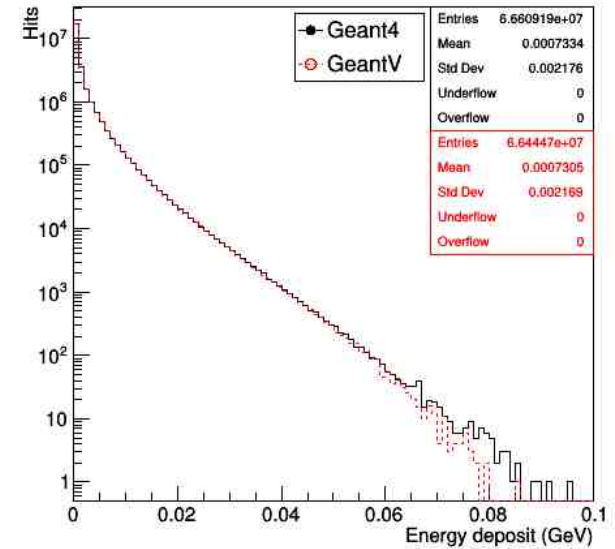
10 GeV Electrons

10 GeV Electrons $B = 0$ EB (Geant4 vs GeantV)



50 GeV Electrons

50 GeV Electrons $B = 0$ EB (Geant4 vs GeantV)

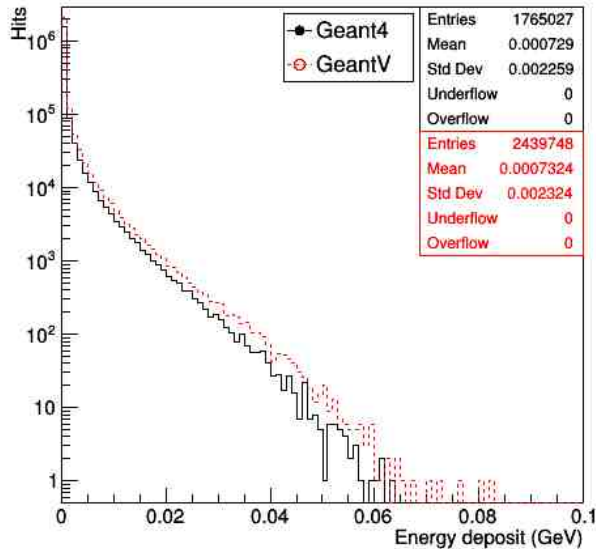


- Number of hits is the same for all 3 energies. The differences are at the level of 0.1/0.3/0.2% for 2, 10 and 50 GeV
- The means differ by 0.8/0.6/0.4% at the three energies

3. Energy Deposit with B = 3.8

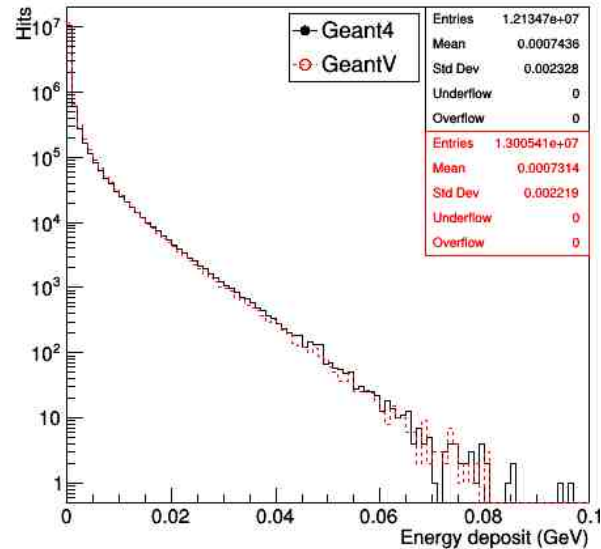
2 GeV Electrons

2 GeV Electrons B = 3.8 Tesla EB (Geant4 vs GeantV)



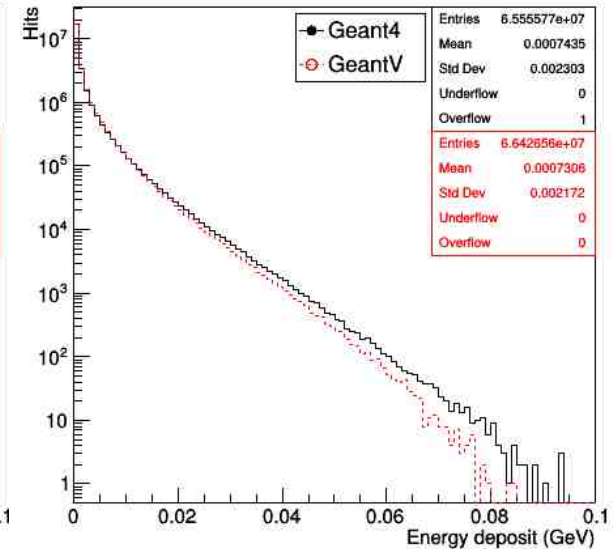
10 GeV Electrons

10 GeV Electrons B = 3.8 Tesla EB (Geant4 vs GeantV)



50 GeV Electrons

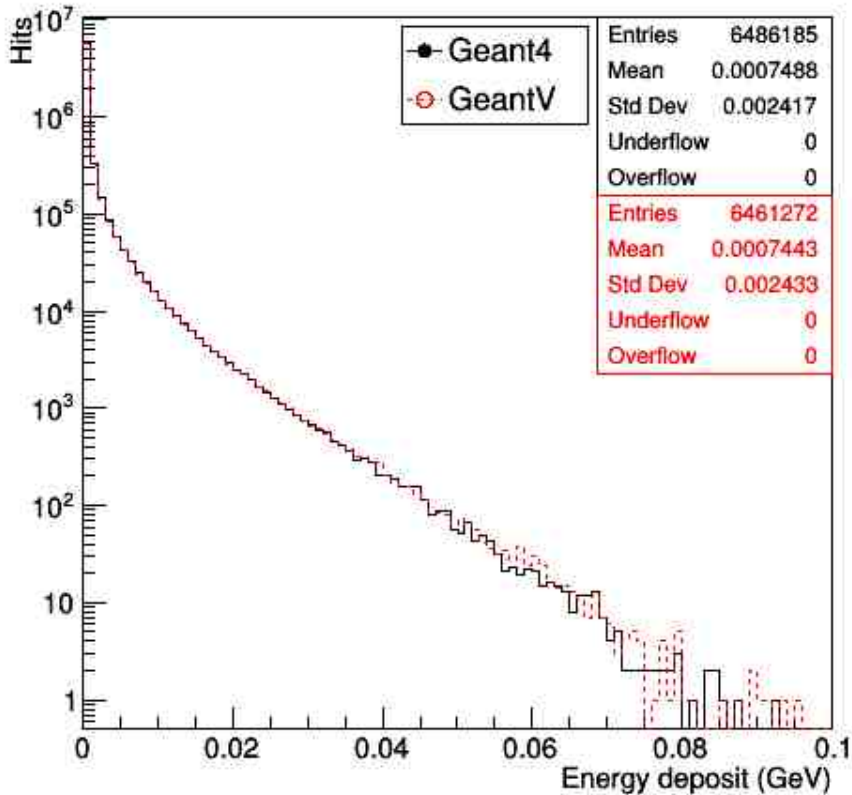
50 GeV Electrons B = 3.8 Tesla EB (Geant4 vs GeantV)



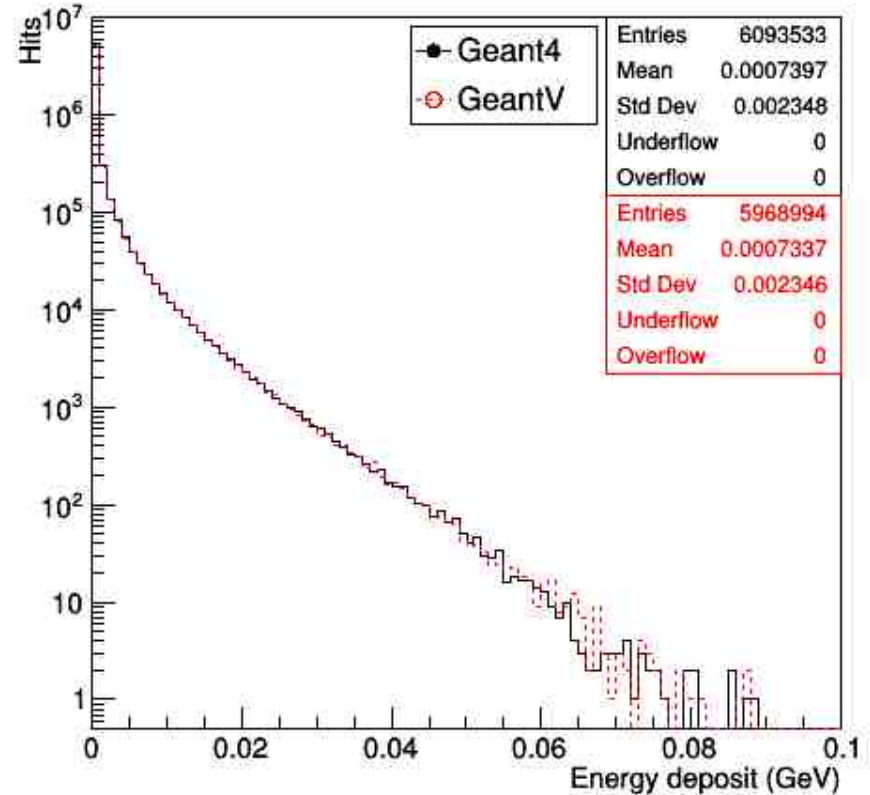
- Number of hits is the same for all 3 energies. The differences are at the level of 27.7/6.7/1.3% for 2, 10 and 50 GeV
- The means differ by 0.5/1.6/1.7% at the three energies

4. Energy Deposit with $B = 0$, MT

50 GeV Electrons $B = 0$ MultiThreads EB (Geant4 vs GeantV)



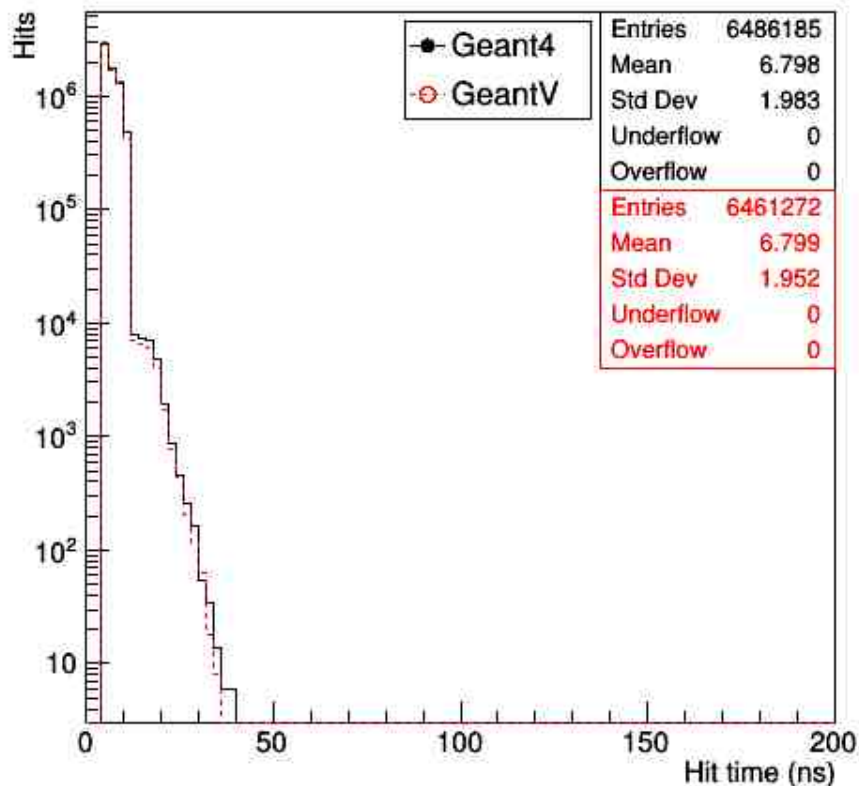
50 GeV Electrons $B = 0$ MultiThreads EE (Geant4 vs GeantV)



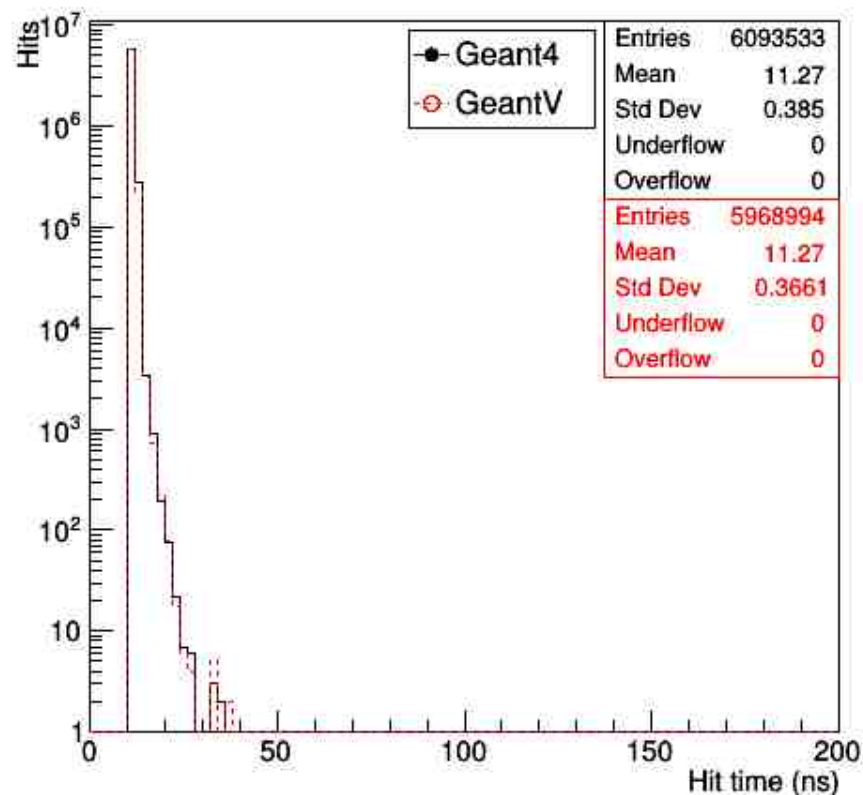
- Events are generated with 50 GeV electrons having random direction within a limited range of η and ϕ
- The agreement is pretty good in the $B=0$ option for both # of hits as well as in the shape of the distributions for EB and EE

4. Hit Times with $B = 0$, MT

50 GeV Electrons $B = 0$ MultiThreads EB (Geant4 vs GeantV)



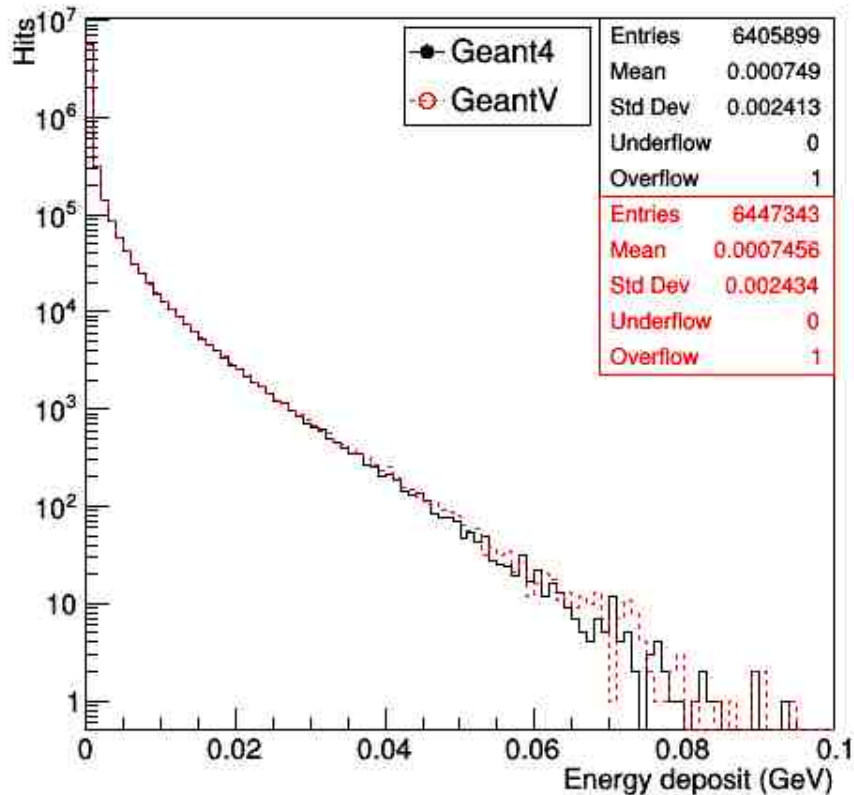
50 GeV Electrons $B = 0$ MultiThreads EE (Geant4 vs GeantV)



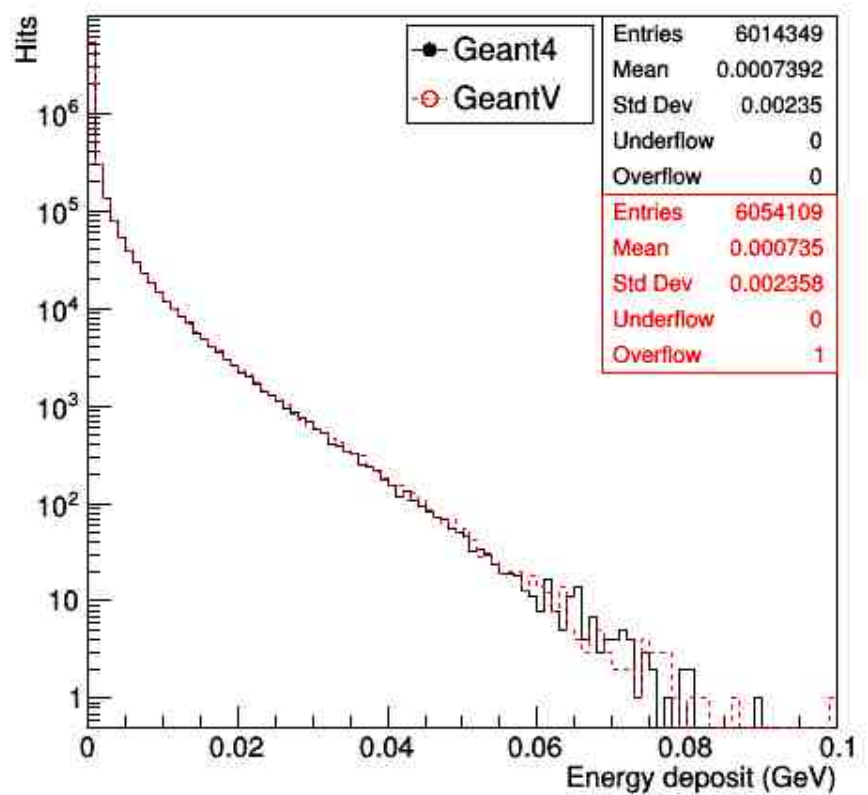
- Hit time distributions are also in good agreement for the $B=0$ option in EB as well as in EE

5. Energy Deposit with $B = 3.8$, MT

50 GeV Electrons B = 3.8 Tesla MultiThreads EB (Geant4 vs GeantV)



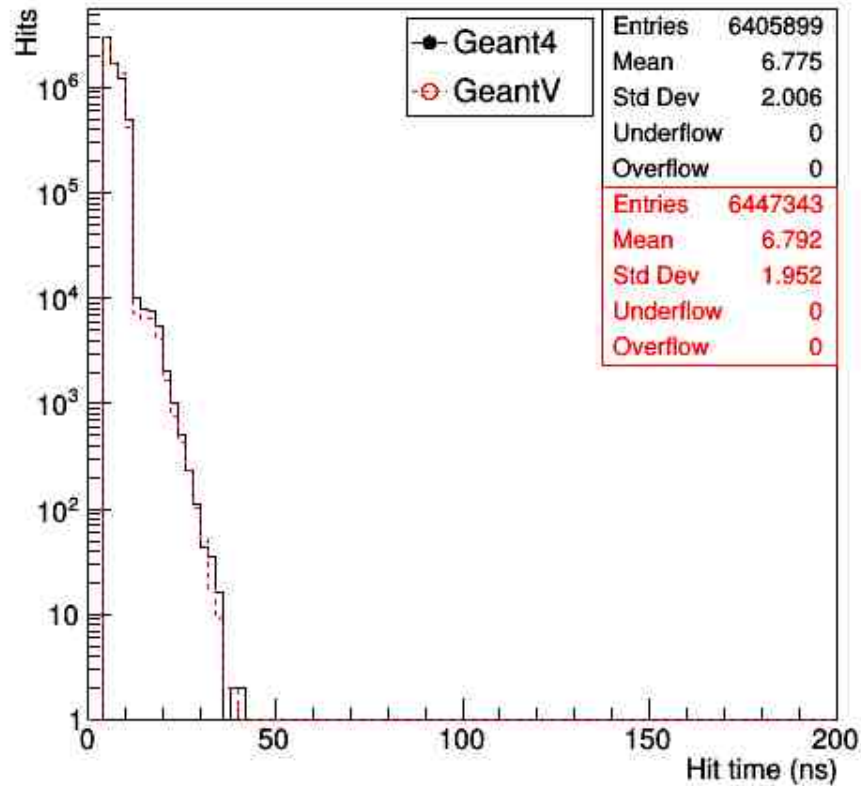
50 GeV Electrons B = 3.8 Tesla MultiThreads EE (Geant4 vs GeantV)



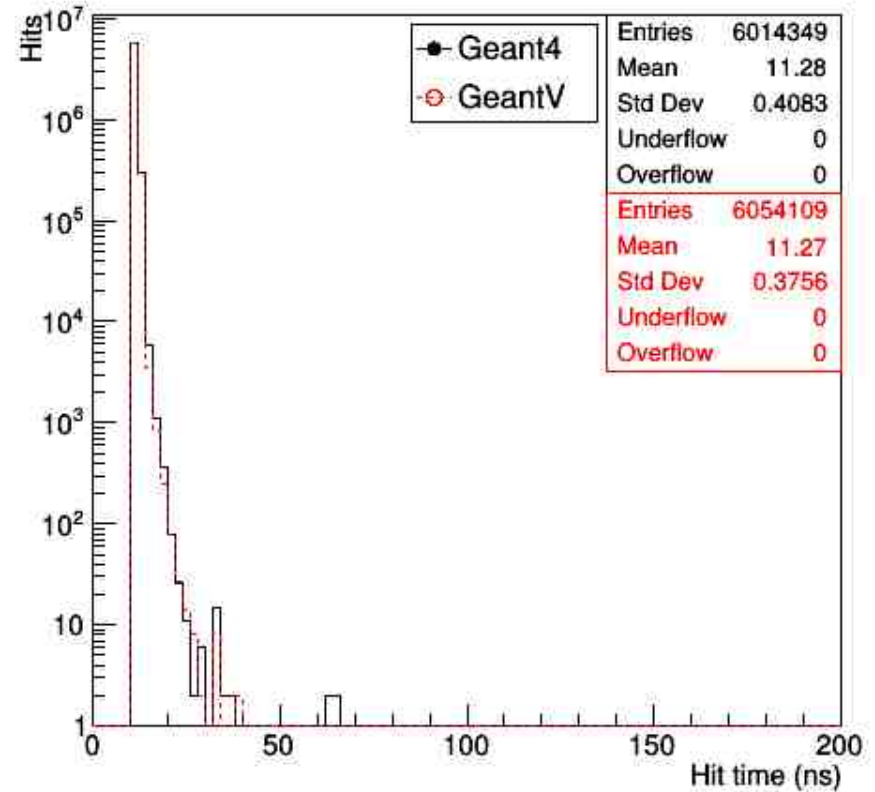
- Same events (50 GeV electrons, random direction within a limited range of η and ϕ) are simulated in a uniform B-field option of 3.8 Tesla
- The agreement is still good for both # of hits as well as in the shape of the distributions for EB and EE

5. Hit Times with $B = 3.8$, MT

50 GeV Electrons B = 3.8 Tesla MultiThreads EB (Geant4 vs GeantV)



50 GeV Electrons B = 3.8 Tesla MultiThreads EE (Geant4 vs GeantV)

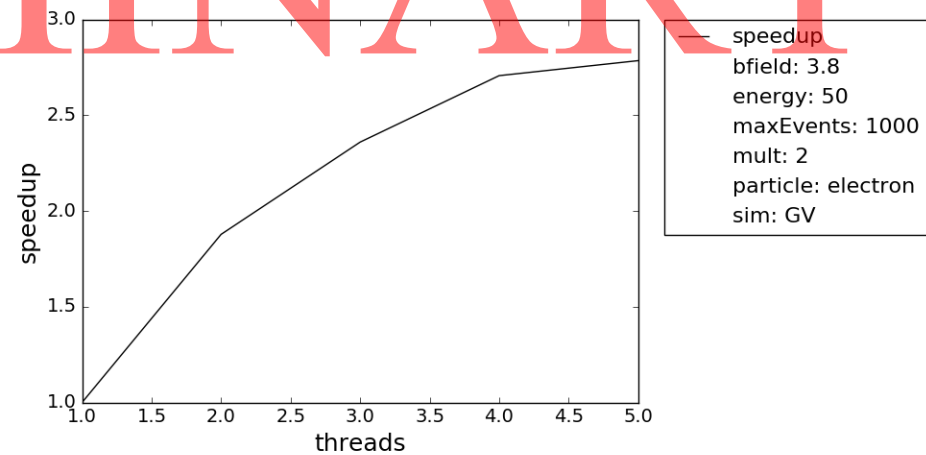
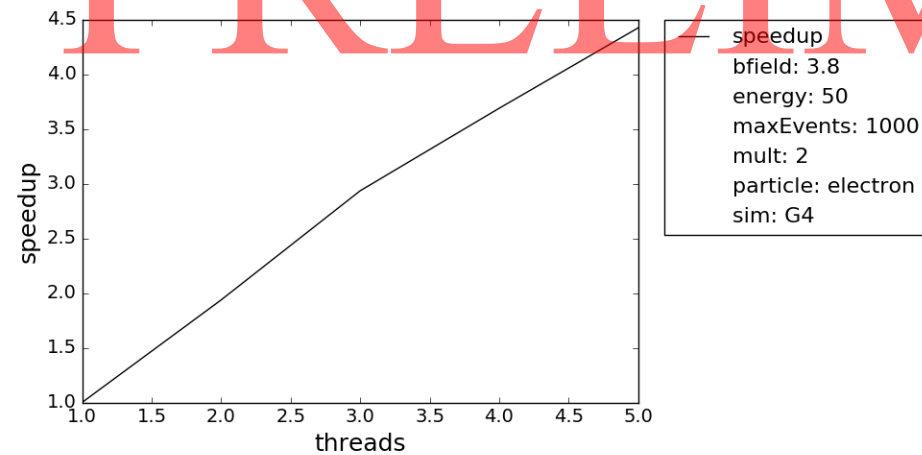
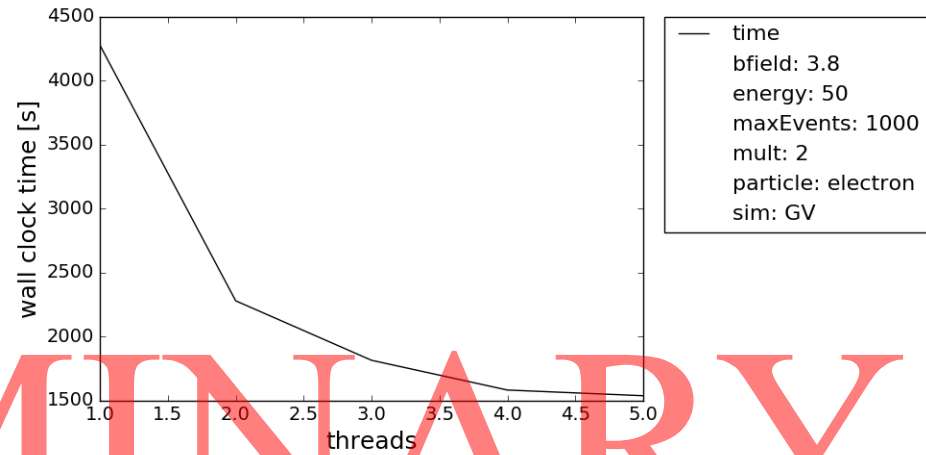
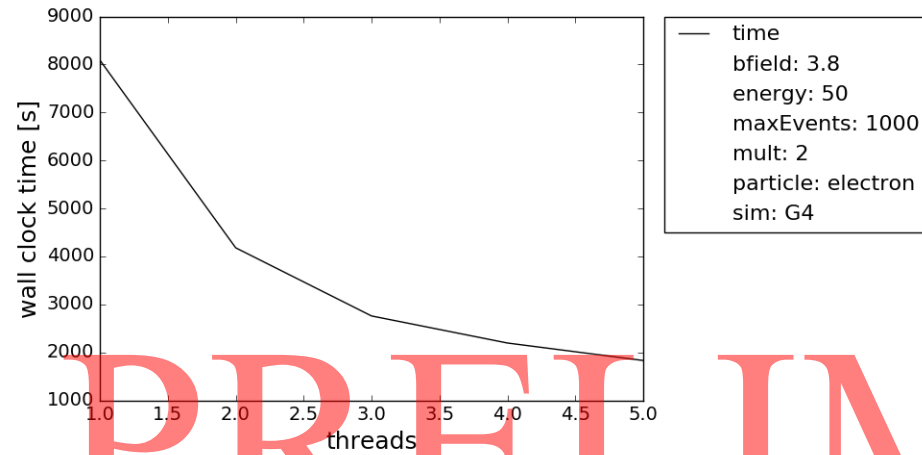


- Hit time distributions are also in reasonable agreement for the $B = 3.8$ Tesla option in EB as well as in EE

Performance Tests

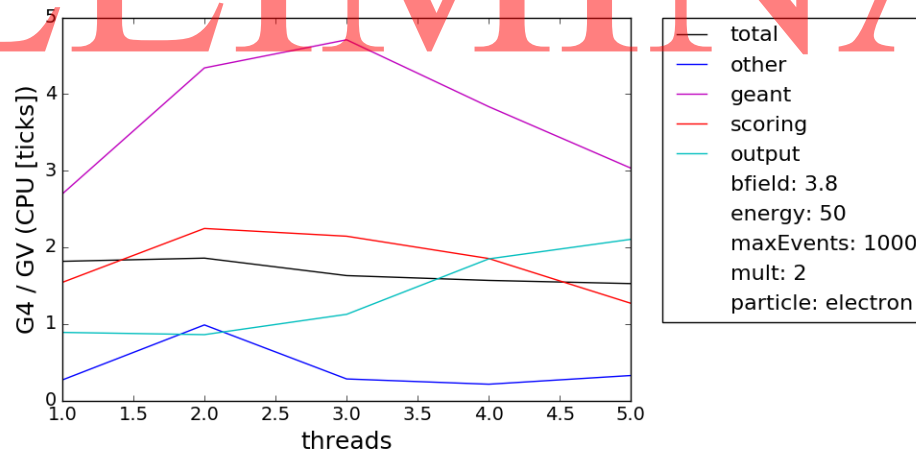
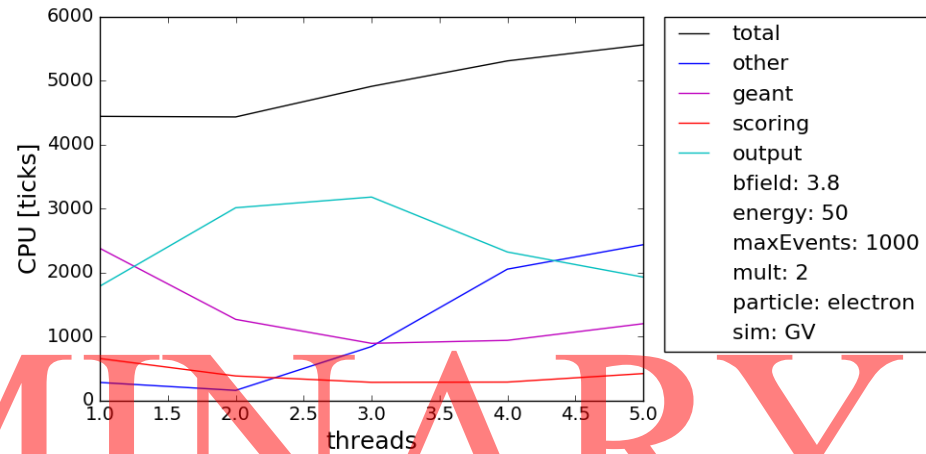
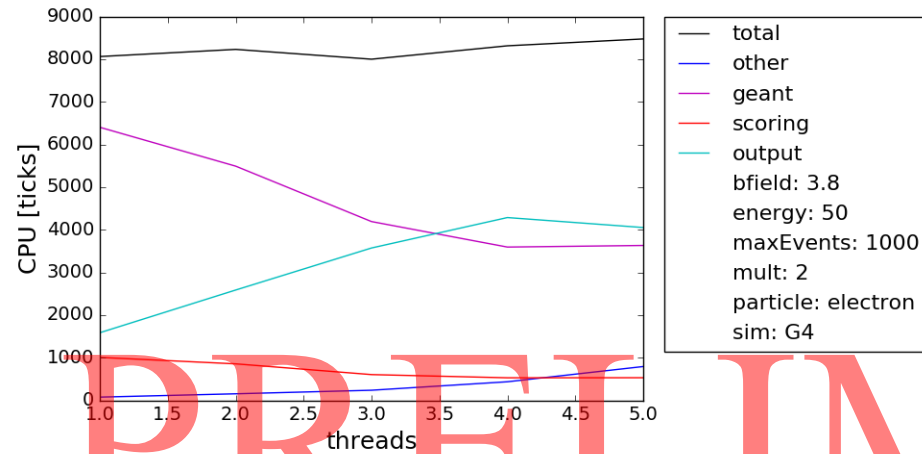
- Compare GeantV and Geant4 CPU usage simulating exact same generated 1000 events (2 electrons w/ $E = 50$ GeV, random directions)
- Running on FermiCloud VM with:
 - Intel(R) Xeon(R) CPU E5-2660 v2 @ 2.20GHz
 - sse4.2 instructions
- Keep other threads busy when running MT tests
- Track memory with CMSSW TimeMemoryInfo tool
 - Measures VSIZE, RSS per event
 - Also measures wall clock time → calculate speedup
- Track CPU usage with igprof (measures all threads together):
 - total = other + geant + output
 - other = initialization, overhead, etc.
 - geant = event loop in Geant4 or GeantV code
 - scoring = subset of event loop in user code
 - output = writing hits to CMSSW EDM ROOT file

Time Performance



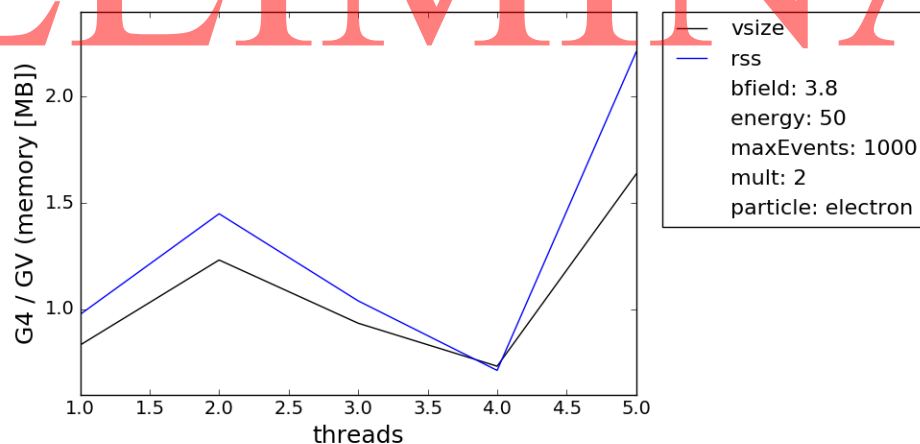
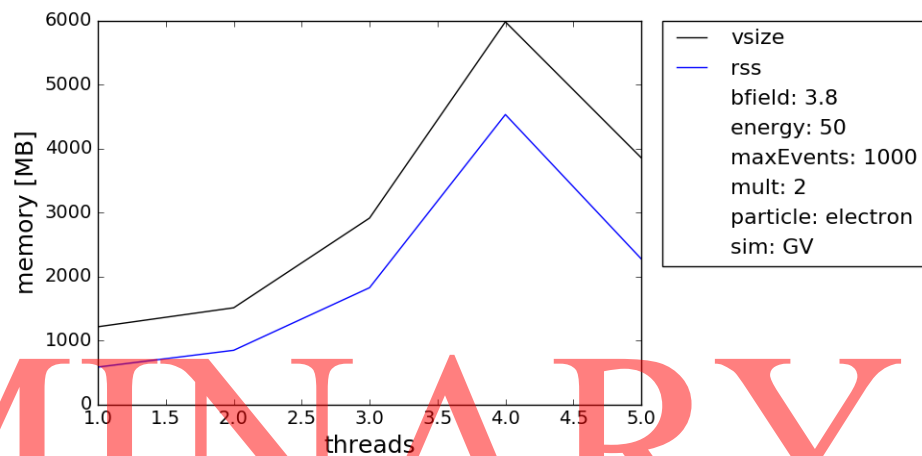
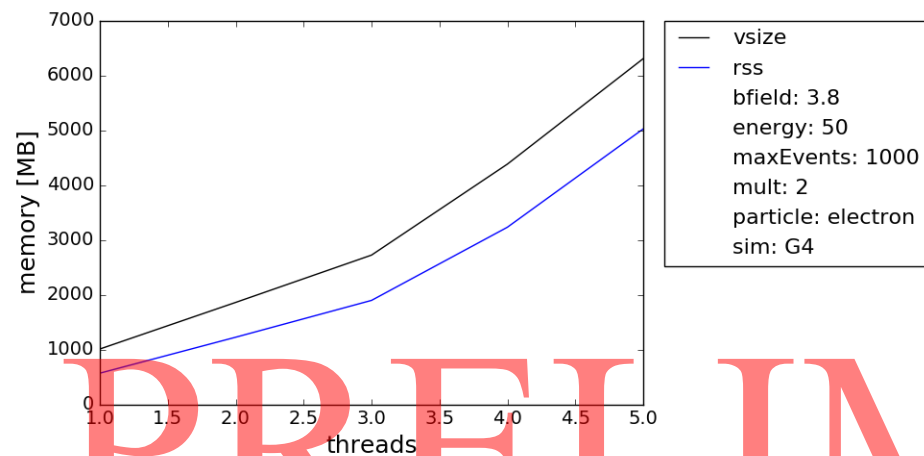
- G4 has better scaling w/ # threads than GV (expected?)

CPU Performance



- GV close to factor of 2 better than G4 in total CPU usage
 - $\sim 3\times$ in event loop, $\sim 2\times$ in scoring, similar in output, worse in initialization

Memory Performance



- Expected GV to use more memory than G4
- True for 1 thread, but not for MT → dominated by output?
- Some fluctuations observed in GV, to be investigated
- Memory overhead from duplicated ScoringClass instances can be optimized

Outlook

- Demonstrator of first “full” GeantV-CMSSW integration is ready
 - Major remaining item: magnetic field map
- “Rosetta stone” mostly contained in StepWrapper and VolumeWrapper:

Geant4	GeantV
<u>StepWrapper</u>	<u>StepWrapper</u>
<u>VolumeWrapper</u>	<u>VolumeWrapper</u>

- Physics validation nearly complete
 - Gaining confidence that G4 and GV are simulating the same things
- Now starting to test computing performance
- Promising early results!

Backup

Template Wrappers

- **Goal:** use *exact same* SD code for Geant4 and GeantV
- **Problem:** totally incompatible APIs
 - Example: `G4Step::GetTotalEnergyDeposit()` VS. `geant::Track::Edep()`
- **Solution:** template wrapper with unified interface
 - e.g. `StepWrapper<T>::getEnergyDeposit()`
 - SD code *only calls* the wrapper
 - Wrapper stores pointer to T (minimize overhead)
- **Current wrappers:**
 - BeginRun
 - BeginEvent
 - Step
 - Volume
 - EndEvent
 - EndRun

Traits

- Collect Geant4/GeantV-specific types and wrappers into unified **Traits** class:

```
struct G4Traits {
    typedef G4Step Step;
    typedef sim::StepWrapper<Step> StepWrapper;
};
struct GVTraits {
    typedef geant::Track Step;
    typedef sim::StepWrapper<Step> StepWrapper;
};
```

- Provides standardized typenames to be used by SD class:

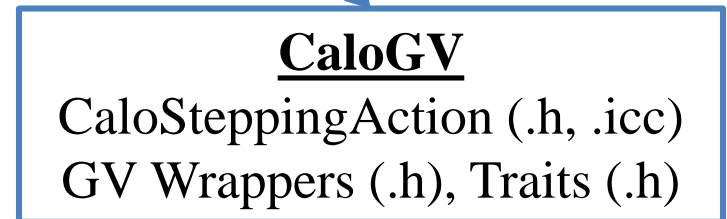
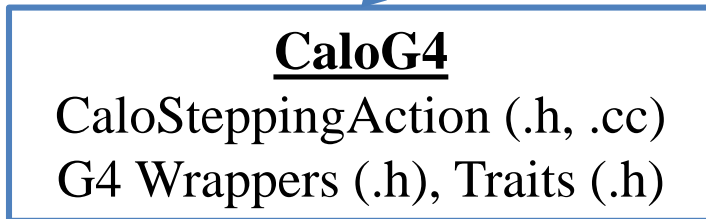
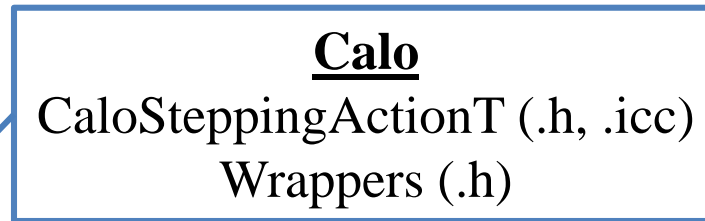
```
template <class Traits> class CaloSteppingActionT : ...,
    public Observer<const typename Traits::Step *>
{
    public:
        void update(const Step * step) override {
update(StepWrapper(step)); }
    private:
        // subordinate functions with unified interfaces
        void update(const StepWrapper& step);
};
```


Organization

Old



New



- SD interface & implementation in **Calo** (.icc file), w/ unimplemented wrapper interfaces
- G4/GV wrapper specializations in **CaloG4/GV**, w/ specific instances of templated SD class → isolate dependencies

Scoring Approaches

- Two approaches to scoring in CMSSW:
 1. Inherit from **G4VSensitiveDetector** (Geant4 class)
 - automatically initialized for geometry volumes marked as sensitive
 2. Inherit from **SimWatcher** (CMSSW standalone class)
 - need to specify names of watched geometry volumes
- CaloSteppingAction is a demonstrator class w/ approach 2
 - Simplified version of ECAL and HCAL scoring
 - Less dependent on Geant4 interfaces
- “Real” SD code uses approach 1
 - More work to extract Geant4 dependencies will be necessary
 - Some SD class methods directly from Geant4 (via inheritance)
 - Need to mock up Geant4-esque interfaces w/ dummy classes for GeantV